

RJH1CV6DPK

1200V - 30A - IGBT Application: Inverter R07DS0747EJ0200 Rev.2.00 Jun 12, 2012

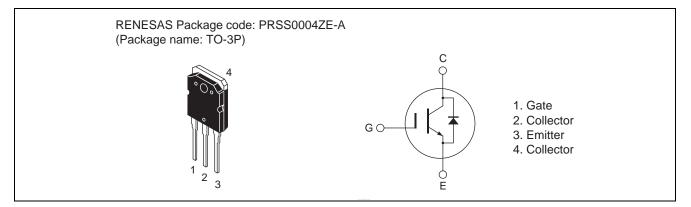
Datasheet

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8 \text{ V typ.}$ (at $I_C = 30 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 180$ ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 120$ ns typ. (at $V_{CC} = 600$ V, $V_{GE} = 15$ V, $I_C = 30$ A, Rg = 5 Ω , $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	1200	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	$Tc = 25^{\circ}C$	Ιc	60	А
	Tc = 100°C	Ιc	30	А
Collector peak current		ic(peak) ^{Note1}	90	А
Collector to emitter diode forward current		I _{DF}	30	А
Collector to emitter diode forward peak current		i _{DF} (peak) ^{Note1}	90	А
Collector dissipation		Pc ^{Note2}	290	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.43	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



Electrical Characteristics

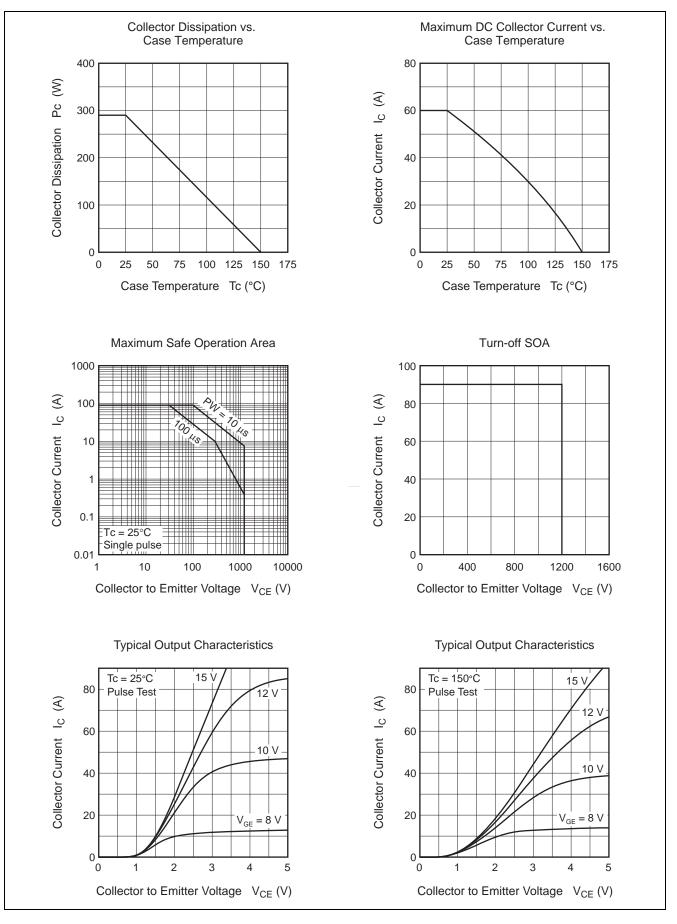
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	V _{(BR)CES}	1200	—	—	V	$I_{C} = 10 \ \mu A, \ V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	I _{CES} /I _R	_	—	5	μA	$V_{CE} = 1200 \text{ V}, \text{ V}_{GE} = 0$
Gate to emitter leak current	I _{GES}	_	—	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V _{GE(off)}	4.5	—	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}		1.8	2.6	V	$I_{C} = 30 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V _{CE(sat)}	_	2.6	_	V	$I_{C} = 60 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies		1600	—	pF	$V_{CE} = 25 V$ $V_{GE} = 0$ $f = 1 MHz$
Output capacitance	Coes	_	85	_	pF	
Reverse transfer capacitance	Cres	_	43	—	pF	
Total gate charge	Qg	_	105	—	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 35 A
Gate to emitter charge	Qge	_	14	—	nC	
Gate to collector charge	Qgc	_	55	—	nC	
Turn-on delay time	t _{d(on)}	_	46	—	ns	$V_{CC} = 600 V$ $V_{GE} = 15 V$ $I_C = 30 A$ $Rg = 5 \Omega$ Inductive load
Rise time	tr	_	33	—	ns	
Turn-off delay time	t _{d(off)}	_	125	—	ns	
Fall time	t _f	_	120	—	ns	
Turn-on energy	Eon		2.3	_	mJ	
Turn-off energy	E _{off}	_	1.7	—	mJ	
Total switching energy	E _{total}		4.0	—	mJ	
Short circuit withstand time	t _{sc}	_	5	—	μs	$\label{eq:V_CC} \begin{array}{l} V_{CC} \leq 720 \ \text{V}, \ V_{GE} = 15 \ \text{V} \\ Tc \leq 125^{\circ}\text{C} \end{array}$
ERD forward voltage	Ve		2.0	I	V	$I_{r} = 30 \text{ A}^{\text{Note3}}$

FRD forward voltage	V _F		2.0	—	V	$I_F = 30 A^{Note3}$
FRD reverse recovery time	t _{rr}	_	180	—	ns	I _F = 30 A
FRD reverse recovery charge	Qrr	_	0.63	—	μC	di _F /dt = 100 A/µs
FRD peak reverse recovery current	l _{rr}	_	9.2	—	А	

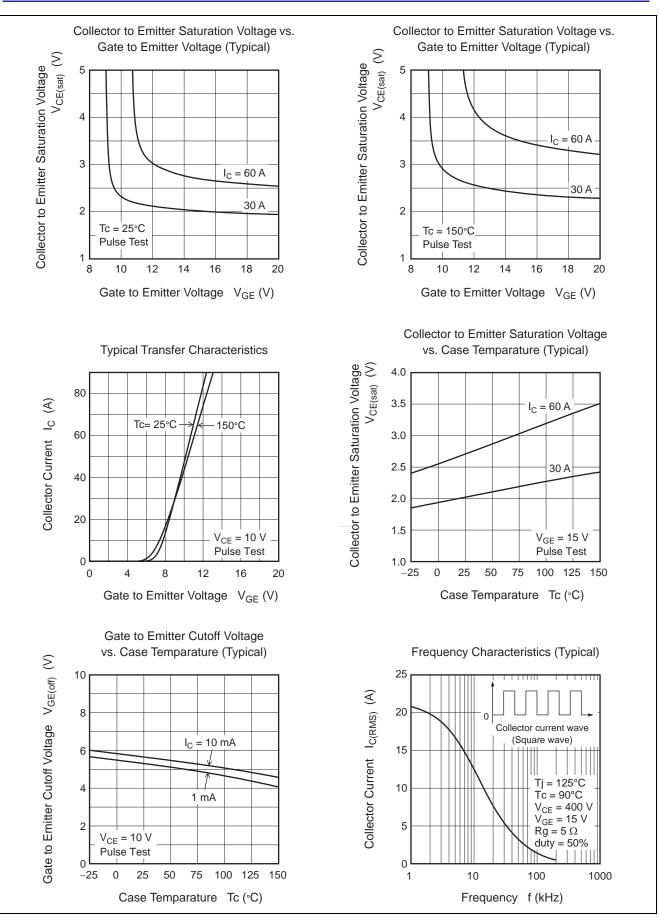
Notes: 3. Pulse test.

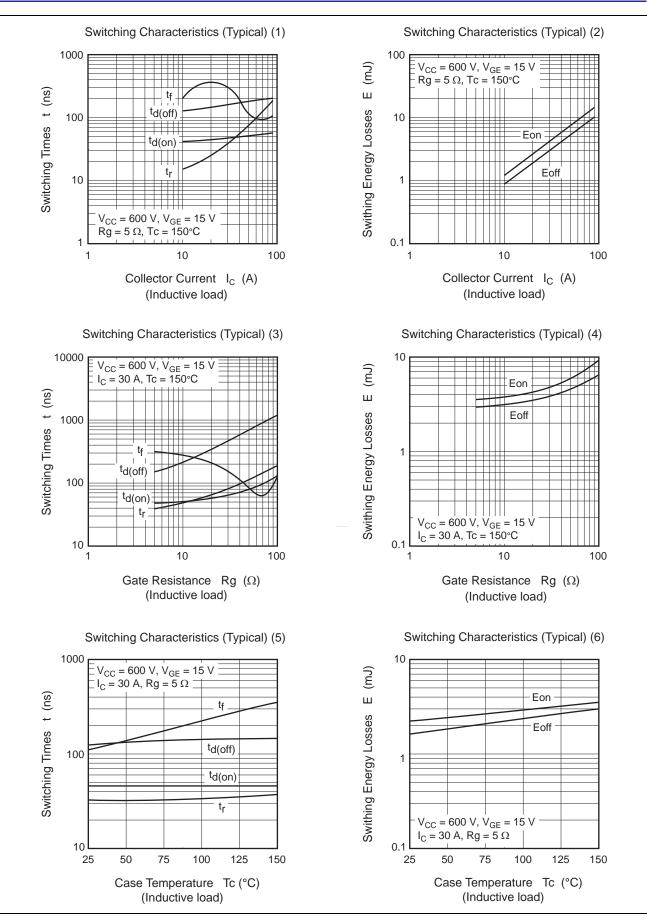


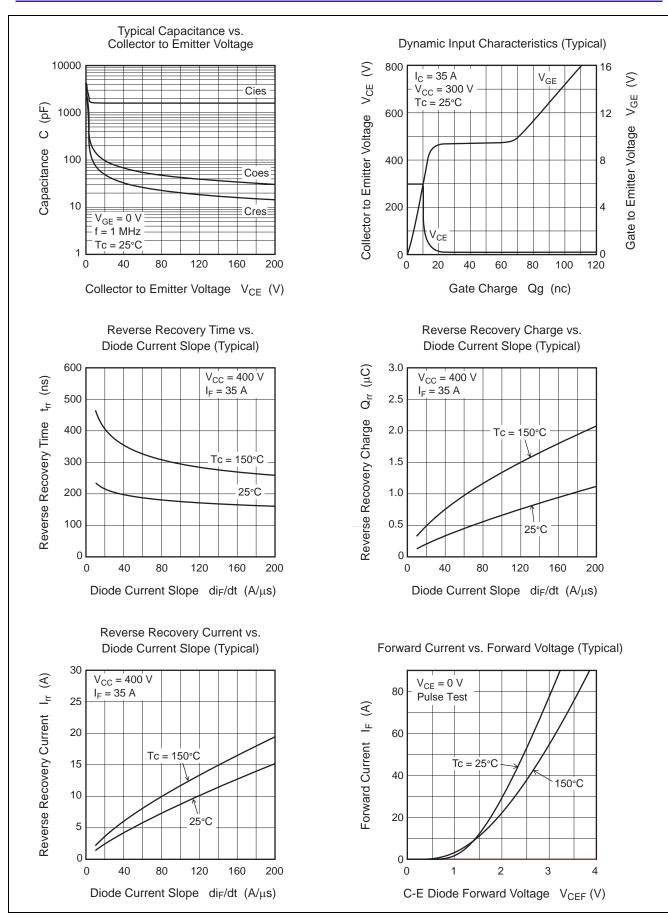
Main Characteristics



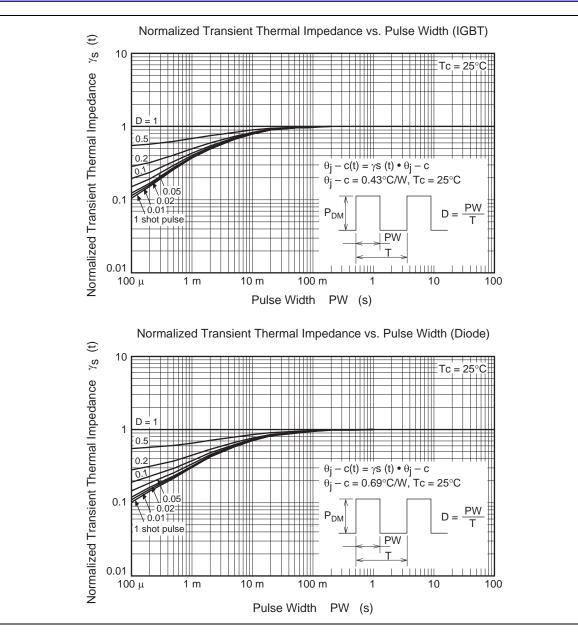




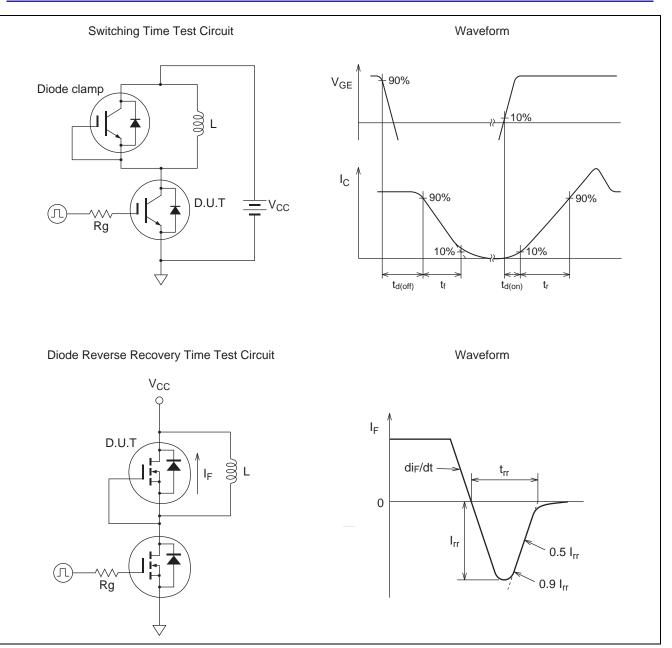














Package Dimension

Package Name TO-3P	JEITA Package Code SC-65	RENESAS Code	Previous Code TO-3P / TO-3PV	MASS[Typ.]	
10-3P	SC-65	PRSS0004ZE-A 15.6 ± 0.3	1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2 1.0 ± 0.2	5.0g 4.8 ± 0.2 1.5 0.6 ± 0.2	Unit: mm
	<u>5.45 ± 0</u>		<u>2</u> .0 <u>1</u> <u>5.45 ± 0.5</u>		

Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CV6DPK-00#T0	360 pcs	Box (Tube)



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